



01-04-02

PATENT  
Docket No: ACT-307DVA

A

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

J10/036303 pro  
12/28/01

Group Art Unit: Not yet assigned      Examiner: Not yet assigned

Serial No. Not yet assigned      Filed: December 28, 2001

In re Application of: Hawley et al.

For: METHOD FOR FABRICATING A MOS TRANSISTOR HAVING IMPROVED  
TOTAL RADIATION-INDUCED LEAKAGE CURRENT

*Certificate of Express Mailing*

*I hereby certify that this correspondence is being deposited with the United States Postal Service  
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Director of Patents, Box New Application, Washington, D.C. 20231  
on 12/28/01, Signed* Stephanie Davis

*Stephanie Davis*

**CONTINUING APPLICATION TRANSMITTAL LETTER**  
37 C.F.R. § 1.53(b)

Director of Patents  
Box New Application  
Washington, D.C. 20231

Dear Sir:

This is a request for filing under the Continuing Application Procedure, 37 C.F.R. § 1.53(b); for a divisional application of prior application Serial No. 09/741,949, filed December 20, 2000, naming inventors Frank Hawley and Daniel Wang. The prior application is assigned of record to Actel Corporation. Enclosed for filing are 12 pages specification, 3 pages of claims, 4 sheets drawings and one page abstract. Also enclosed is a Preliminary Amendment and a Request for Non-Publication.

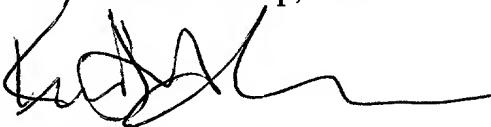
The attorney's Docket Number of this application is ACT-307DVA.

Kindly address all communications regarding this application to:

Kenneth D'Alessandro  
Sierra Patent Group, Ltd.  
P.O. Box 6149  
Stateline, NV 89449  
(775) 586-9500

No fee is being paid at this time.

Respectfully submitted,  
Sierra Patent Group, Ltd.



Kenneth D'Alessandro  
Reg. No. 29,144

Dated: December 28, 2001  
Sierra Patent Group, Ltd.  
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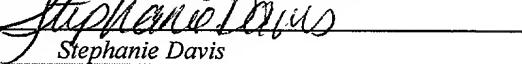
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*Stephanie Davis*

**REQUEST FOR NONPUBLICATION PURSUANT TO 37 C.F.R. § 1.213**

Director of Patents  
Washington, D.C. 20231

Sir:

Applicant hereby requests that this application not be published under 35 U.S.C. §122(b). Applicant certifies that the invention disclosed in the application has not been and will not be the subject of an application filed in another country, or under a multilateral agreement, that requires publication at eighteen months after filing.

Respectfully submitted,  
Sierra Patent Group, Ltd.



Kenneth D'Alessandro  
Reg. No.: 29,144

Dated: December 28, 2001

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